



*(Use several sheets if necessary)*

**PTGF-03093**

**Not Yet Assigned**

Masanobu Senda, et al.

**FILING**

**Concurrently Herewith**

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## U.S. PATENT DOCUMENTS

[illegible]

## FOREIGN PATENT DOCUMENTS

[illegible]

**OTHER DOCUMENTS** (Including Author, Title, Date, Pertinent Pages, Etc.)

DM			Kazuyuki Tadatomo, et al., "High Output Power InGaN Ultraviolet Light-Emitting Diodes Fabricated on Patterned Substrates Using Metalorganic Vapor Phase Epitaxy", Japanese Journal of Applied Physics, Vol. 40, June 15, 2001, pp. L583-L585.
DM			Motokazu Yamada, et al., "InGaN-Based Near-Ultraviolet and Blue-Light-Emitting Diodes with High External Quantum Efficiency Using a Patterned Sapphire Substrate and a Mesh Electrode", Japanese Journal of Physics, Vol. 41, December 15, 2002, pp. L1431-L1433.

**EXAMINER**

**DATE CONSIDERED**

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.